
Initial Information Data Sheet

Applicant Information

Applicant Authority Type:: Inventor
Applicant One Given Name:: Yi-Hsun
Family Name:: Wu
Postal Address Line One:: 6F-1, No. 26, Lane 467, Sec II
Postal Address Line Two:: Guang-Fu Rd.
City:: Hsin-Chu
Country:: Taiwan, R.O.C.
Country of Residence:: Taiwan, R.O.C.
Citizenship Country:: Taiwan, R.O.C.

Applicant Authority Type:: Inventor
Applicant Two Given Name:: Jian-Hsing
Family Name:: Lee
Postal Address Line One:: No. 11, Po-San Rd.
City:: Hsin-Chu
Country:: Taiwan, R.O.C.
Country of Residence:: Taiwan, R.O.C.
Citizenship Country:: Taiwan, R.O.C.

Applicant Authority Type:: Inventor
Applicant Three Given Name:: Tongchern
Family Name:: Ong
Postal Address Line One:: 3F, No. 2, Lane 86
Postal Address Line Two:: Min-Hsiang St.
City:: Chung-Ho City
Country:: Taipei
Country of Residence:: Taipei
Citizenship Country:: Taiwan, R.O.C.

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Correspondence Information

Correspondence Customer Number::27683

Application Information

Title Line One:: ELECTROSTATIC DISCHARGE PROTECTION
Title Line Two:: STRUCTURE FOR DEEP SUB-MICRON
Title Line Three:: GATE OXIDE
Total Drawing Sheets:: 6
Formal Drawings?: Yes
Application Type:: Utility
Docket Number:: 24061.27 / TSMC2002-1168

Representative Information

Registration Number:: 42,044

Assignee Information

Assignee Name:: Taiwan Semiconductor Manufacturing Co., Ltd.
Street of mailing address:: No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park
City:: Hsin-Chu
Country of mailing address:: Taiwan, R.O.C.
Postal or Zip Code:: 300-77

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